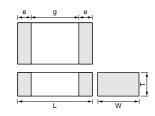
Monolithic Ceramic Capacitors GR_R6/R7/F5/E4 (X5R/X7R/Y5V/Z5U)

High Dielectric Constant Type 6.3/16/25/50V





| Part Number | | Dir | nensions (n | nm) | | |
|-------------|-----------|-----------|-------------|-------------|--------|--|
| Part Number | L | W | T | е | g min. | |
| GRM155 | 1.0 ±0.05 | 0.5 ±0.05 | 0.5 ±0.05 | 0.15 to 0.3 | 0.4 | |
| GRM188* | 1.6 ±0.1 | 0.8 ±0.1 | 0.8 ±0.1 | 0.2 to 0.5 | 0.5 | |
| GRM216 | | | 0.6 ±0.1 | | 0.7 | |
| GRM219 | 2.0 ±0.1 | 1.25 ±0.1 | 0.85 ±0.1 | 0.2 to 0.7 | | |
| GRM21B | | | 1.25 ±0.1 | | | |
| GRM319 | 2 2 10 15 | 1 4 10 15 | 0.85 ±0.1 | | 1.5 | |
| GRM31M | 3.2 ±0.15 | 1.0 ±0.15 | 1.15 ±0.1 | 0.3 to 0.8 | | |
| GRM31C | 3.2 ±0.2 | 1.6 ±0.2 | 1.6 ±0.2 | | | |

^{*} Bulk Case : $1.6 \pm 0.07(L) \times 0.8 \pm 0.07(W) \times 0.8 \pm 0.07(T)$

| Part Number | TC Code | Rated Voltage (Vdc) | Capacitance* | Length L (mm) | Width W (mm) | Thickness T (mm) |
|-------------------|-----------|------------------------|--------------|------------------|-----------------|---------------------|
| GRM155R61A683KA01 | X5R (EIA) | 10 | 68000pF±10% | 1.0 | 0.5 | 0.50 |
| GRM155R61A104KA01 | X5R (EIA) | 10 | 0.1μF±10% | 1.0 | 0.5 | 0.50 |
| GRM188R61A334KA61 | X5R (EIA) | 10 | 0.33 μF±10% | 1.6 | 0.8 | 0.80 |
| GRM188R61A474KA61 | X5R (EIA) | 10 | 0.47μF±10% | 1.6 | 0.8 | 0.80 |
| GRM188R61A684KA61 | X5R (EIA) | 10 | 0.68μF±10% | 1.6 | 0.8 | 0.80 |
| GRM188R61A105KA61 | X5R (EIA) | 10 | 1μF ±10% | 1.6 | 0.8 | 0.80 |
| GRM188R60J105KA01 | X5R (EIA) | 6.3 | 1μF ±10% | 1.6 | 0.8 | 0.80 |
| GRM219R61A105KC01 | X5R (EIA) | 10 | 1μF ±10% | 2.0 | 1.25 | 0.90 |
| GRM21BR61A225KA01 | X5R (EIA) | 10 | 2.2μF ±10% | 2.0 | 1.25 | 1.25 |
| GRM219R60J155KC01 | X5R (EIA) | 6.3 | 1.5μF ±10% | 2.0 | 1.25 | 0.90 |
| GRM21BR60J225KA01 | X5R (EIA) | 6.3 | 2.2μF ±10% | 2.0 | 1.25 | 1.25 |
| GRM21BR60J335KA11 | X5R (EIA) | 6.3 | 3.3μF ±10% | 2.0 | 1.25 | 1.25 |
| GRM21BR60J475KA11 | X5R (EIA) | 6.3 | 4.7μF ±10% | 2.0 | 1.25 | 1.25 |
| GRM319R61A225KC01 | X5R (EIA) | 10 | 2.2μF ±10% | 3.2 | 1.6 | 0.90 |
| GRM31XR61A335KC12 | X5R (EIA) | 10 | 3.3μF ±10% | 3.2 | 1.6 | 1.30 |
| GRM31CR61A475KA01 | X5R (EIA) | 10 | 4.7μF ±10% | 3.2 | 1.6 | 1.60 |
| GRM31MR60J475KC11 | X5R (EIA) | 6.3 | 4.7μF ±10% | 3.2 | 1.6 | 1.15 |
| GRM31CR61A106KA01 | X5R (EIA) | 10 | 10μF ±10% | 3.2 | 1.6 | 1.60 |
| GRM31CR60J106KA01 | X5R (EIA) | 6.3 | 10μF ±10% | 3.2 | 1.6 | 1.60 |
| GRM31CR60J226ME20 | X5R (EIA) | 6.3 | 22μF ±20% | 3.2 | 1.6 | 1.60 |
| GRM32ER61A106KC01 | X5R (EIA) | 10 | 10μF ±10% | 3.2 | 2.5 | 2.50 |
| GRM55DR61H106KA01 | X5R (EIA) | 50 | 10μF ±10% | 5.7 | 5.0 | 2.00 |
| GRM15XR71H221KA86 | X7R (EIA) | 50 | 220pF±10% | 1.0 | 0.5 | 0.25 |
| GRM155R71H221KA01 | X7R (EIA) | 50 | 220pF±10% | 1.0 | 0.5 | 0.50 |
| GRM15XR71H331KA86 | X7R (EIA) | 50 | 330pF±10% | 1.0 | 0.5 | 0.25 |
| GRM155R71H331KA01 | X7R (EIA) | 50 | 330pF±10% | 1.0 | 0.5 | 0.50 |
| GRM15XR71H471KA86 | X7R (EIA) | 50 | 470pF±10% | 1.0 | 0.5 | 0.25 |
| GRM155R71H471KA01 | X7R (EIA) | 50 | 470pF±10% | 1.0 | 0.5 | 0.50 |
| GRM15XR71H681KA86 | X7R (EIA) | 50 | 680pF±10% | 1.0 | 0.5 | 0.25 |
| GRM155R71H681KA01 | X7R (EIA) | 50 | 680pF±10% | 1.0 | 0.5 | 0.50 |
| GRM15XR71H102KA86 | X7R (EIA) | 50 | 1000pF±10% | 1.0 | 0.5 | 0.25 |
| GRM155R71H102KA01 | X7R (EIA) | 50 | 1000pF±10% | 1.0 | 0.5 | 0.50 |
| GRM15XR71H152KA86 | X7R (EIA) | 50 | 1500pF±10% | 1.0 | 0.5 | 0.25 |
| GRM155R71H152KA01 | X7R (EIA) | 50 | 1500pF±10% | 1.0 | 0.5 | 0.50 |
| GRM155R71H222KA01 | X7R (EIA) | 50 | 2200pF±10% | 1.0 | 0.5 | 0.50 |



| Part Number | TC Code | Rated Voltage (Vdc) | Capacitance* | Length L (mm) | Width W (mm) | Thickness T (mm) | |
|-------------------|------------------------|------------------------|--------------|------------------|-----------------|---------------------|--|
| GRM155R71H332KA01 | X7R (EIA) | 50 | 3300pF±10% | 1.0 | 0.5 | 0.50 | |
| GRM155R71H472KA01 | X7R (EIA) | 50 | 4700pF±10% | 1.0 | 0.5 | 0.50 | |
| GRM15XR71E182KA86 | X7R (EIA) | 25 | 1800pF±10% | 1.0 | 0.5 | 0.25 | |
| RM15XR71E222KA86 | X7R (EIA) | 25 | 2200pF±10% | 1.0 | 0.5 | 0.25 | |
| RM155R71E682KA01 | X7R (EIA) | 25 | 6800pF±10% | 1.0 | 0.5 | 0.50 | |
| RM155R71E103KA01 | X7R (EIA) | 25 | 10000pF±10% | 1.0 | 0.5 | 0.50 | |
| RM15XR71C332KA86 | X7R (EIA) | 16 | 3300pF±10% | 1.0 | 0.5 | 0.25 | |
| RM15XR71C472KA86 | X7R (EIA) | 16 | 4700pF±10% | 1.0 | 0.5 | 0.25 | |
| RM15XR71C682KA86 | X7R (EIA) | 16 | 6800pF±10% | 1.0 | 0.5 | 0.25 | |
| RM155R71C153KA01 | X7R (EIA) | 16 | 15000pF±10% | 1.0 | 0.5 | 0.50 | |
| RM155R71C223KA01 | X7R (EIA) | 16 | 22000pF±10% | 1.0 | 0.5 | 0.50 | |
| RM155R71A333KA01 | X7R (EIA) | 10 | 33000pF±10% | 1.0 | 0.5 | 0.50 | |
| RM155R71A473KA01 | X7R (EIA) | 10 | 47000pF±10% | 1.0 | 0.5 | 0.50 | |
| RM188R71H221KA01 | X7R (EIA) | 50 | 220pF±10% | 1.6 | 0.8 | 0.80 | |
| RM188R71H331KA01 | X7R (EIA) | 50 | 330pF±10% | 1.6 | 0.8 | 0.80 | |
| RM188R71H471KA01 | X7R (EIA) | 50 | 470pF±10% | 1.6 | 0.8 | 0.80 | |
| RM188R71H681KA01 | X7R (EIA) | 50 | 680pF±10% | 1.6 | 0.8 | 0.80 | |
| RM188R71H102KA01 | X7R (EIA) | 50 | 1000pF±10% | 1.6 | 0.8 | 0.80 | |
| RM188R71H152KA01 | X7R (EIA) | 50 | 1500pF±10% | 1.6 | 0.8 | 0.80 | |
| RM188R71H222KA01 | X7R (EIA) | 50 | 2200pF±10% | 1.6 | 0.8 | 0.80 | |
| GRM188R71H332KA01 | X7R (EIA) | 50 | 3300pF±10% | 1.6 | 0.8 | 0.80 | |
| GRM188R71H472KA01 | X7R (EIA) | 50 | 4700pF±10% | 1.6 | 0.8 | 0.80 | |
| GRM188R71H682KA01 | X7R (EIA) | 50 | 6800pF±10% | 1.6 | 0.8 | 0.80 | |
| RM188R71H103KA01 | X7R (EIA) | 50 | 10000pF±10% | 1.6 | 0.8 | 0.80 | |
| RM188R71H153KA01 | X7R (EIA) | 50 | 15000pF±10% | 1.6 | 0.8 | 0.80 | |
| RM188R71H223KA01 | X7R (EIA) | 50 | 22000pF±10% | 1.6 | 0.8 | 0.80 | |
| RM188R71E333KA01 | X7R (EIA) | 25 | 33000pF±10% | 1.6 | 0.8 | 0.80 | |
| RM188R71E473KA01 | X7R (EIA) | 25 | 47000pF±10% | 1.6 | 0.8 | 0.80 | |
| RM188R71E683KA01 | X7R (EIA) | 25 | 68000pF±10% | 1.6 | 0.8 | 0.80 | |
| RM188R71E104KA01 | X7R (EIA) | 25 | 0.1μF±10% | 1.6 | 0.8 | 0.80 | |
| RM188R71C104KA01 | X7R (EIA) | 16 | 0.1μF±10% | 1.6 | 0.8 | 0.80 | |
| RM188R71A154KA01 | X7R (EIA) | 10 | 0.15μF±10% | 1.6 | 0.8 | 0.80 | |
| GRM188R71A224KA01 | X7R (EIA) | 10 | 22000pF±10% | 1.6 | 0.8 | 0.80 | |
| GRM219R71H333KA01 | X7R (EIA) | 50 | 33000pF±10% | 2.0 | 1.25 | 0.90 | |
| GRM21BR71H473KA01 | X7R (EIA) | 50 | 47000pF±10% | 2.0 | 1.25 | 1.25 | |
| | | 50 | • | 2.0 | | 1.25 | |
| RM21BR71H683KA01 | X7R (EIA) | 50 | 68000pF±10% | | 1.25 | | |
| GRM21BR71H104KA01 | X7R (EIA) X7R (EIA) | | 0.1μF±10% | 2.0 | 1.25 | 1.25 1.25 | |
| RM21BR71H154KA01 | , , | 50 | 0.15μF±10% | 2.0 | 1.25 | | |
| RM21BR71H224KA01 | X7R (EIA) | 50 | 22000pF±10% | 2.0 | 1.25 | 1.25 | |
| RM21BR71E104KA01 | X7R (EIA) | 25 | 0.1μF±10% | 2.0 | 1.25 | 1.25 | |
| RM21BR71E154KA01 | X7R (EIA) | 25 | 0.15μF±10% | 2.0 | 1.25 | 1.25 | |
| RM219R71E224KC01 | X7R (EIA) | 25 | 22000pF±10% | 2.0 | 1.25 | 0.90 | |
| RM21BR71E334KC01 | X7R (EIA) | 25 | 0.33 μF±10% | 2.0 | 1.25 | 1.25 | |
| RM21BR71E474KC01 | X7R (EIA) | 25 | 0.47μF±10% | 2.0 | 1.25 | 1.25 | |
| RM219R71C474KC01 | X7R (EIA) | 16 | 0.47μF±10% | 2.0 | 1.25 | 0.90 | |
| RM219R71C684KC01 | X7R (EIA) | 16 | 0.68μF±10% | 2.0 | 1.25 | 0.90 | |
| RM21BR71C105KA01 | X7R (EIA) | 16 | 1μF ±10% | 2.0 | 1.25 | 1.25 | |
| RM319R71H334KA01 | X7R (EIA) | 50 | 0.33 μF±10% | 3.2 | 1.6 | 0.90 | |
| RM31MR71H474KA01 | X7R (EIA) | 50 | 0.47μF±10% | 3.2 | 1.6 | 1.15 | |
| RM319R71E684KC01 | X7R (EIA) | 25 | 0.68μF±10% | 3.2 | 1.6 | 0.90 | |
| RM31MR71E105KC01 | X7R (EIA) | 25 | 1μF ±10% | 3.2 | 1.6 | 1.15 | |
| RM319R71C105KC11 | X7R (EIA) | 16 | 1μF ±10% | 3.2 | 1.6 | 0.90 | |
| GRM31MR71C155KC11 | X7R (EIA) | 16 | 1.5μF ±10% | 3.2 | 1.6 | 1.15 | |
| GRM31MR71C225KA35 | X7R (EIA) | 16 | 2.2μF ±10% | 3.2 | 1.6 | 1.15 | |
| GRM319R71A105KC01 | X7R (EIA) | 10 | 1μF ±10% | 3.2 | 1.6 | 0.90 | |



| Part Number | TC Code | Rated Voltage (Vdc) | Capacitance* | Length L (mm) | Width W (mm) | Thickness T (mm) |
|-------------------|-----------|------------------------|--------------------|------------------|-----------------|---------------------|
| GRM319R71A225KA01 | X7R (EIA) | 10 | 2.2μF ±10% | 3.2 | 1.6 | 0.90 |
| GRM32NR71H684KA01 | X7R (EIA) | 50 | 0.68μF±10% | 3.2 | 2.5 | 1.35 |
| GRM32RR71H105KA01 | X7R (EIA) | 50 | 1μF ±10% | 3.2 | 2.5 | 1.80 |
| GRM32RR71E225KC01 | X7R (EIA) | 25 | 2.2μF ±10% | 3.2 | 2.5 | 1.80 |
| GRM32MR71C225KC01 | X7R (EIA) | 16 | 2.2μF ±10% | 3.2 | 2.5 | 1.15 |
| GRM32NR71C335KC01 | X7R (EIA) | 16 | 3.3μF ±10% | 3.2 | 2.5 | 1.35 |
| RM32RR71C475KC01 | X7R (EIA) | 16 | 4.7μF ±10% | 3.2 | 2.5 | 1.80 |
| RM43ER71H225KA01 | X7R (EIA) | 50 | 2.2μF ±10% | 4.5 | 3.2 | 2.50 |
| RM55RR71H105KA01 | X7R (EIA) | 50 | 1μF ±10% | 5.7 | 5.0 | 1.80 |
| RM55RR71H155KA01 | X7R (EIA) | 50 | 1.5μF ±10% | 5.7 | 5.0 | 1.80 |
| RM155F51H222ZA01 | Y5V (EIA) | 50 | 2200pF +80%, -20% | 1.0 | 0.5 | 0.50 |
| RM155F51H472ZA01 | Y5V (EIA) | 50 | 4700pF +80%, -20% | 1.0 | 0.5 | 0.50 |
| RM155F51H103ZA01 | Y5V (EIA) | 50 | 10000pF +80%, -20% | 1.0 | 0.5 | 0.50 |
| RM155F51E223ZA01 | Y5V (EIA) | 25 | 22000pF +80%, -20% | 1.0 | 0.5 | 0.50 |
| RM155F51C473ZA01 | Y5V (EIA) | 16 | 47000pF +80%, -20% | 1.0 | 0.5 | 0.50 |
| RM155F51C104ZA01 | Y5V (EIA) | 16 | 10000pF +80%, -20% | 1.0 | 0.5 | 0.50 |
| RM188F51H103ZA01 | Y5V (EIA) | 50 | 10000pF +80%, -20% | 1.6 | 0.8 | 0.80 |
| RM188F51H223ZA01 | Y5V (EIA) | 50 | 22000pF +80%, -20% | 1.6 | 0.8 | 0.80 |
| RM188F51H473ZA01 | Y5V (EIA) | 50 | 47000pF +80%, -20% | 1.6 | 0.8 | 0.80 |
| RM188F51H104ZA01 | Y5V (EIA) | 50 | 10000pF +80%, -20% | 1.6 | 0.8 | 0.80 |
| RM188F51E104ZA01 | Y5V (EIA) | 25 | 10000pF +80%, -20% | 1.6 | 0.8 | 0.80 |
| RM188F51C224ZA01 | Y5V (EIA) | 16 | 22000pF +80%, -20% | 1.6 | 0.8 | 0.80 |
| RM188F51C474ZA01 | Y5V (EIA) | 16 | 0.47µF +80%, -20% | 1.6 | 0.8 | 0.80 |
| RM188F51A474ZC01 | , , | 10 | | 1.6 | 0.8 | 0.80 |
| | Y5V (EIA) | | 0.47μF +80%, -20% | | 0.8 | 0.80 |
| RM188F51A105ZA01 | Y5V (EIA) | 10 | 1μF +80%, -20% | 1.6 | | |
| RM219F51H104ZA01 | Y5V (EIA) | 50 | 10000pF +80%, -20% | 2.0 | 1.25 | 0.90 |
| RM21BF51H224ZA01 | Y5V (EIA) | 50 | 22000pF +80%, -20% | 2.0 | 1.25 | 1.25 |
| RM219F51E224ZA01 | Y5V (EIA) | 25 | 22000pF +80%, -20% | 2.0 | 1.25 | 0.90 |
| RM21BF51E474ZA01 | Y5V (EIA) | 25 | 0.47μF +80%, -20% | 2.0 | 1.25 | 1.25 |
| RM219F51E105ZA01 | Y5V (EIA) | 25 | 1μF +80%, -20% | 2.0 | 1.25 | 0.90 |
| RM21BF51E225ZA01 | Y5V (EIA) | 25 | 2.2μF +80%, -20% | 2.0 | 1.25 | 1.25 |
| RM219F51C105ZA01 | Y5V (EIA) | 16 | 1μF +80%, -20% | 2.0 | 1.25 | 0.90 |
| RM21BF51C225ZA01 | Y5V (EIA) | 16 | 2.2μF +80%, -20% | 2.0 | 1.25 | 1.25 |
| RM219F51A105ZA01 | Y5V (EIA) | 10 | 1μF +80%, -20% | 2.0 | 1.25 | 0.90 |
| RM21BF51A225ZA01 | Y5V (EIA) | 10 | 2.2μF +80%, -20% | 2.0 | 1.25 | 1.25 |
| RM21BF51A475ZA01 | Y5V (EIA) | 10 | 4.7μF +80%, -20% | 2.0 | 1.25 | 1.25 |
| RM31MF51H474ZA01 | Y5V (EIA) | 50 | 0.47μF +80%, -20% | 3.2 | 1.6 | 1.15 |
| RM31MF51E105ZA01 | Y5V (EIA) | 25 | 1μF +80%, -20% | 3.2 | 1.6 | 1.15 |
| RM31MF51E475ZA01 | Y5V (EIA) | 25 | 4.7μF +80%, -20% | 3.2 | 1.6 | 1.15 |
| RM319F51C105ZA01 | Y5V (EIA) | 16 | 1μF +80%, -20% | 3.2 | 1.6 | 0.90 |
| RM31MF51C225ZA01 | Y5V (EIA) | 16 | 2.2μF +80%, -20% | 3.2 | 1.6 | 1.15 |
| RM31MF51C475ZA12 | Y5V (EIA) | 16 | 4.7μF +80%, -20% | 3.2 | 1.6 | 1.15 |
| RM319F51A225ZA01 | Y5V (EIA) | 10 | 2.2μF +80%, -20% | 3.2 | 1.6 | 0.90 |
| RM31MF51A475ZA01 | Y5V (EIA) | 10 | 4.7μF +80%, -20% | 3.2 | 1.6 | 1.15 |
| RM31MF51A106ZA01 | Y5V (EIA) | 10 | 10μF +80%, -20% | 3.2 | 1.6 | 1.15 |
| RM31MF50J106ZA01 | Y5V (EIA) | 6.3 | 10μF +80%, -20% | 3.2 | 1.6 | 1.15 |
| RM32RF51H105ZA01 | Y5V (EIA) | 50 | 1μF +80%, -20% | 3.2 | 2.5 | 1.80 |
| RM329F51E475ZA01 | Y5V (EIA) | 25 | 4.7μF +80%, -20% | 3.2 | 2.5 | 0.90 |
| RM32NF51E106ZA01 | Y5V (EIA) | 25 | 10μF +80%, -20% | 3.2 | 2.5 | 1.35 |
| RM32NF51C106ZA01 | Y5V (EIA) | 16 | 10μF +80%, -20% | 3.2 | 2.5 | 1.35 |
| RM188E41H103MA01 | Z5U (EIA) | 50 | 10000pF±20% | 1.6 | 0.8 | 0.80 |
| RM188E41H223MA01 | Z5U (EIA) | 50 | 22000pF±20% | 1.6 | 0.8 | 0.80 |
| RM216E41H473MA01 | Z5U (EIA) | 50 | 47000pF±20% | 2.0 | 1.25 | 0.60 |
| RM219E41H104MA01 | Z5U (EIA) | 50 | 10000pF±20% | 2.0 | 1.25 | 0.90 |
| RM319E41H224MA01 | Z5U (EIA) | 50 | 22000pF±20% | 3.2 | 1.6 | 0.90 |

■ Specifications and Test Methods

| | | Specifi | cations | | | | |
|-----|------------------------------------|---|--|--|--|--|--|
| No. | Item | Temperature Compensating Type | High Dielectric Type | Test Method | | | |
| 1 | Operating Temperature Range | –55 to +125℃ | B1, B3, F1: -25°C to +85°C R1, R7: -55°C to +125°C E4: +10°C to +85°C F5: -30°C to +85°C | Reference Temperature : 25°C (2 Δ , 3 Δ , 4 Δ , B1, B3, F1, R1 : 20°C) | | | |
| 2 | Rated Voltage | See the previous pages | | The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, VP-P or VO-P, whichever is larger, should be maintained within the rated voltage range. | | | |
| 3 | Appearance | No defects or abnormalities | | Visual inspection | | | |
| 4 | Dimensions | Within the specified dimensions | 1 | Using calipers | | | |
| 5 | Dielectric Strength | No defects or abnormalities | | No failure should be observed when 300% of the rated voltage (temperature compensating type) or 250% of the rated voltage (high dielectric constant type) is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA. | | | |
| 6 | Insulation Resistance | C≦0.047μF : More than 10,0000 C>0.047μF : 500Ω • F | MΩ C : Nominal Capacitance | The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at 20°C/25°C and 75%RH max. and within 2 minutes of charging, provided the charge/discharge current is less than 50mA. | | | |
| 7 | Capacitance | Within the specified tolerance | | The capacitance/D.F. should be measured at 20°C/25°C at the | | | |
| 8 | Q/ Dissipation Factor (D.F.) | 30pF and over : Q≥1000 30pF and below : Q≥400+20C C : Nominal Capacitance (pF) | [B1, B3, R1, R6, R7, E4] W.V.: 25Vmin.: 0.025max. W.V.: 16/10V: 0.035max. W.V.: 6.3V/4V : 0.05max. (C<3.3μF) : 0.1max. (C≧3.3μF) [F1, F5] W.V.: 25Vmin. : 0.05max. (C<0.1μF) : 0.09max. (C≥0.1μF) W.V.: 16V/10V: 0.125max. W.V.: 6.3V: 0.15max. | Char. ΔC to ΔU, 1X (more than 1000pF) E4 E4 E7 E7 E7 E7 E7 E7 | | | |





| | | om the prec | | ications | | | |
|-----|---|----------------------|---|--|---|--|--|
| No. | lt∈ | em | Temperature Compensating Type | High Dielectric Type | | Test Method | |
| | | No bias | Within the specified tolerance (Table A-1) | B1, B3 : Within±10% (-25°C to +85°C) R1, R7 : Within±15% (-55°C to +125°C) R6 : Within±15% (-55°C to +85°C) E4 : Within ±22/-56% (+10°C to +85°C) F1 : Within +30/-80% (-25°C to +85°C) F5 : Within +22/-82% (-30°C to +85°C) | each speci (1)Temper The temper measured When cycliffs (5C: +2) coeffs: +2 should be coefficient The capac | itance change should be meified temp. stage. ature Compensating Type trature coefficient is determined in step 3 as a reference. So to +125°C/AC: +20°C to 25°C to +85°C/+20°C to +85°C/+40°C to +85°C to +80°C | and using the capacitance it is it |
| | | | | | · · | nd 5 by the cap. value in ste | - |
| | | 50% of the Rated | | B1 : Within +10/-30% R1 : Within +15/-40% | | | erature (℃) Femperature±2 |
| | | Voltage | | F1 : Within +30/–95% | | | -25±3 (for other TC) |
| | | | | | | Reference | Temperature±2 |
| | | | | / | | | 85±3 (for other TC) |
| | | | | | | 5 Reference | Temperature±2 |
| 9 | Capacitance Temperature Characteristics | | | | The ranges value over be within the In case of measured | ielectric Constant Type s of capacitance change con the temperature ranges sho ne specified ranges.* applying voltage, the capacit after 1 more min. with apply on of each temp. stage. | wn in the table should tance change should be |
| | | | | | Step | Temperature (°C) | Applying Voltage (V) |
| | | Capacitance Drift | within ±0.2% or ±0.05pF (Whichever is larger.) *Not apply to 1X/25V | *Initial measurement for high | 2 3 | Reference Tempereture± -55±3 (for R1, R7, R6) -25±3 (for B1, B3, F1) -30±3 (for F5)/10±3 (for E Reference Tempereture± | 4) No bias |
| | | | | dielectric constant type Perform a heat treatment at 150+0/-10°C for one hour | 4 | 125±3 (for R1, R7)/ 85±3 (for B1, B3, R6 F1, F5, E4) | |
| | | | | and then set for 48±4 hours | 5 | Reference Tempereture± | 2 |
| | | | | at room temperature. Perform the initial measurement. | 6 | -55±3 (for R1)/ -25±3 (for B1, F1) | 50% of the rated |
| | | | | measurement. | 7 | Reference Tempereture± | - |
| | | | | | 8 | 125±3 (for R1)/ 85±3 (for B1, F1) | |
| | | | No removal of the terminations | or other defect should occur | Fig. 1a using parallel with The solder reflow methes soldering is | capacitor to the test jig (glasing an eutectic solder. Then is the test jig for 10±1 sec. ing should be done either withod and should be conductes uniform and free of defects 103), 5N (GR□15, GRM18) | apply 10N* force in th an iron or using the d with care so that the |
| | | | | | | | (in mm) |
| 10 | Adhesive of Termin | Strength | | | Ту | | b c |
| | or remin | เสเเปไ | | | _GR□03 GR□15 | | 0.9 0.3 1.5 0.5 |
| | | | | Solder resist | GR∐18 | | 3.0 1.2 |
| | | | | Baked electrode or | GRM21 | 1 1.2 | 4.0 1.65 |
| | | | | copper foil | GRM31 | | 5.0 2.0 |
| | | | Fig. 1a | | GRM32 GRM43 | | 5.0 2.9 7.0 3.7 |
| | | | | | GRIVI43 | J.U.U | 0.1 |
| | | | | | GRM55 | | 8.0 5.6 |

$\begin{tabular}{|c|c|c|c|}\hline \end{tabular}$ Continued from the preceding page.

| | | om the prec | | cations | | | | |
|-----|---------------------------------------|---------------------------|--|--|--|---|--|-------------------|
| No. | lte | em | Temperature Compensating Type | High Dielectric Type | - | Test Me | thod | |
| | | Appearance Capacitance | No defects or abnormalities Within the specified tolerance | [B1, B3, R1, R6, R7, E4] | Solder the capa | citor on the test jig | ı (glass epo | xy board) in the |
| 11 | Vibration Resistance | Q/D.F. | 30pF and over : Q≥1000 30pF and below : Q≥400+20C C : Nominal Capacitance (pF) | W.V.: 25Vmin.: 0.025max. W.V.: 16/10V: 0.035max. W.V.: 6.3V/4V : 0.05max. (C<3.3μF) : 0.1max. (C≥3.3μF) [F1, F5] W.V.: 25Vmin. : 0.05max. (C<0.1μF) : 0.09max. (C≥0.1μF) W.V.: 16V/10V: 0.125max. W.V.: 6.3V: 0.15max. | The capacitor should be subjected to a simple harmonic m having a total amplitude of 1.5mm, the frequency being vai uniformly between the approximate limits of 10 and 55Hz. frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should applied for a period of 2 hours in each 3 mutually perpendidirections (total of 6 hours). Solder the capacitor on the test jig (glass epoxy board) should be a subject to the capacitor on the test jig (glass epoxy board) should be a subject to the capacitor on the test jig (glass epoxy board) should be a subject to the capacitor on the test jig (glass epoxy board) should be a subject to the capacitor on the test jig (glass epoxy board) should be a subject to the capacitor on the test jig (glass epoxy board) should be a subject to the capacitor on the test jig (glass epoxy board) should be a subject to the capacitor on the test jig (glass epoxy board) should be a subject to the capacitor on the test jig (glass epoxy board) should be a subject to the capacitor of the test jig (glass epoxy board) should be a subject to the capacitor of the test jig (glass epoxy board) should be a subject to the capacitor of the test jig (glass epoxy board) should be a subject to the capacitor of the test jig (glass epoxy board) should be a subject to the capacitor of the capacitor of the test jig (glass epoxy board) should be a subject to the capacitor of the c | | | |
| | | | No crack or marked defect shou | Solder the capacitor on the test jig (glass epoxy board) shown in Fig. 2a using an eutectic solder. Then apply a force in the direction shown in Fig. 3a for 5±1sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free | | | y a force in the oldering should be ethod and should | |
| 12 | 12 Deflection | | 20 50 Pressurizing speed: 1.0mm/sec. Pressurize Pressurize Flexure: ≤1 Capacitance meter 45 Fig. 3a | | Type GR□03 GR□15 GRM18 GRM21 GRM31 GRM32 GRM43 GRM55 | a 0.3 0.4 1.0 1.2 2.2 2.2 3.5 4.5 | | □03/15:t:0.8mm) |
| 13 | Solderab Terminati | | 75% of the terminations are to be continuously The measured and observed ch | ŕ | rosin (JIS-K-590 Preheat at 80 to | 02) (25% rosin in w 0 120°C for 10 to 30 1, immerse in an e | veight propo) seconds. | |
| | | | specifications in the following ta | - | | | | |
| | | Appearance | No defects or abnormalities | | | | | |
| | | Capacitance Change | Within ±2.5% or ±0.25pF (Whichever is larger) | B1, B3, R1, R6, R7 : Within ±7.5% F1, F5, E4 : Within ±20% | Immerse the ca | acitor at 120 to 15 pacitor in an euted ands. Set at room t | tic solder so | olution at 270±5℃ |
| 14 | Resistance to Soldering Heat | Q/D.F. | 30pF and over : Q≥1000 30pF and below : Q≥400+20C C : Nominal Capacitance (pF) | [B1, B3, R1, R6, R7, E4] W.V.: 25Vmin.: 0.025max. W.V.: 16/10V: 0.035max. W.V.: 6.3V/4V : 0.05max. (C<3.3µF) : 0.1max. (C≥3.3µF) [F1, F5] W.V.: 25Vmin. : 0.05max. (C<0.1µF) : 0.09max. (C≥0.1µF) W.V.: 16V/10V: 0.125max. W.V.: 6.3V: 0.15max. | (temperature or constant type), Initial measure Perform a heat then set at room Perform the initial temperature. | 1 100℃ to 120℃ 1 min. | | |
| | | I.R. | More than $10,000 \mathrm{M}\Omega$ or 500Ω | F (Whichever is smaller) | | | | |
| | | Dielectric Strength | No defects | | | | | |

| | | Specifi | ications | | | | | |
|----------------------------------|------------------------|---|--|--|-----------------------------------|---------------|---------------------------|---------------|
| No. Ite | m | Temperature Compensating Type | High Dielectric Type | | Tes | t Method | t | |
| | | The measured and observed chapecifications in the following ta | • | | | | | |
| | Appearance | No defects or abnormalities | | | | | | |
| | Capacitance Change | Within ±2.5% or ±0.25pF (Whichever is larger) | B1, B3, R1, R6, R7 : Within ±7.5% F1, F5, E4 : Within ±20% | Fix the capacitor manner and un Perform the five shown in the fo | der the same e cycles accor | condition | ns as (10). | atments |
| | | | [B1, B3, R1, R6, R7, E4] W.V.: 25Vmin.: 0.025max. W.V.: 16/10V: 0.035max. | Set for 24±2 ho hours (high die measure. | ours (temperat lectric constan | it type) a | t room tempera | iture, ther |
| 15 Temperature | | 30pF and over : Q≧1000 | W.V.: 6.3V/4V | Step | 1 | 2 | 3 | 4 |
| Cycle | Q/D.F. | 30pF and below : Q≧400+20C | : 0.05max. (C<3.3µF) : 0.1max. (C≥3.3µF) | Temp. (℃) | Min. Operating Temp.+0/-3 | Room Temp. | Max. Operating Temp.+3/-0 | Room Temp. |
| | | C : Nominal Capacitance (pF) | W.V. : 25Vmin. | Time (min.) | 30±3 | 2 to 3 | 30±3 | 2 to 3 |
| ī | LP More than | | : 0.05max. (C<0.1µF) : 0.09max. (C≧0.1µF) W.V.: 16V/10V: 0.125max. W.V.: 6.3V: 0.15max. | Initial measurement for high dielectric constant type Perform a heat treatment at 150+0/−10°C for one hour and then set at room temperature for 48±4 hours. Perform the initial measurement. | | | | |
| | I.R. | More than $10,000M\Omega$ or 500Ω | | | | | | |
| | Dielectric Strength | No defects | | | | | | |
| | | The measured and observed chapecifications in the following ta | | | | | | |
| | Appearance | No defects or abnormalities | | | | | | |
| | Capacitance Change | Within ±5% or ±0.5pF (Whichever is larger) | B1, B3, R1, R6, R7, C8 : Within ±12.5% F1, F5 : Within ±30% | | | | | |
| Humidity 16 (Steady State) | Q/D.F. | 30pF and over : Q≧350 10pF and over 30pF and below : Q≥275+2.5C 10pF and below : Q≥200+10C | [B1, B3, R1, R6, R7, E4] W.V.: 25Vmin.: 0.05max. W.V.: 16/10V: 0.05max. W.V.: 6.3V/4V : 0.075max. (C≤3.3µF) : 0.125max. (C≧3.3µF) [F1, F5] W.V.: 25Vmin. | Set the capacitor at 40±2℃ and in 90 to 95% humiduty for 500±12 hours. Remove and set for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. | | | | |
| | | C : Nominal Capacitance (pF) | : 0.075max. (C<0.1µF) : 0.125max. (C≧0.1µF) W.V. : 16V/10V : 0.15max. W.V. : 6.3V : 0.2max. | | | | | |

 $\begin{tabular}{|c|c|c|c|}\hline \end{tabular}$ Continued from the preceding page.

| | | Specifi | ications | | | | |
|------------------------|-----------------------|---|--|---|--|--|--|
| No. | Item | Temperature Compensating Type | High Dielectric Type | Test Method | | | |
| | | The measured and observed chapecifications in the following ta | - | | | | |
| | Appearance | No defects or abnormalities | | | | | |
| | Capacitance Change | Within ±7.5% or ±0.75pF (Whichever is larger) | B1, B3, R1, R6, R7 : Within ±12.5% F1, F5, E4: Within ±30% [W.V.: 10Vmax.] F1, F5: Within +30/-40% | Apply the rated voltage at 40±2°C and 90 to 95% humidity for 500±12 hours. Remove and set for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant | | | |
| 17 Humidi Load | Q/D.F. | 30pF and over : Q≥200 30pF and below : Q≥100+10C/3 C : Nominal Capacitance (pF) | [B1, B3, R1, R6, R7, E4] W.V.: 25Vmin.: 0.05max. W.V.: 16/10V: 0.05max. W.V.: 6.3V : 0.075max. (C<3.3μF) : 0.125max. (C≧3.3μF) [F1, F5] W.V.: 25Vmin. : 0.075max. (C<0.1μF) : 0.125max. (C≥0.1μF) W.V.: 16V/10V: 0.15max. W.V.: 6.3V: 0.2max. | type) at room temprature, then muasure. The charge/disch current is less than 50mA. •Initial measurement for F1, F5/10V max. Apply the rated DC voltage for 1 hour at 40±2°C. Remove and set for 48±4 hours at room temperature. Perform initial measurement. | | | |
| | I.R. | More than 500MΩ or 25Ω • F (V | Vhichever is smaller) | | | | |
| | | The measured and observed chapecifications in the following ta | - | | | | |
| | Appearance | No defects or abnormalities | | | | | |
| | Capacitance Change | Within ±3% or ±0.3pF (Whichever is larger) | B1, B3, R1, R6, R7 : Within ±12.5% F1, F5, E4: Within ±30% [Exept 10Vmax. and. C≥1.0µF] F1, F5: Within +30/-40% [10Vmax. and. C≥1.0µF] | Apply 200% of the rated voltage at the maximum operating temperature ±3°c for 1000±12 hours. Set for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. | | | |
| High 18 Temperatu Load | Q/D.F. | 30pF and over : Q≥350 10pF and over 30pF and below : Q≥275+2.5C 10pF and below : Q≥200+10C C : Nominal Capacitance (pF) | [B1, B3, R1, R6, R7, E4] W.V.: 25Vmin.: 0.04max. W.V.: 16/10V: 0.05max. W.V.: 6.3V : 0.075max.(C≤3.3μF) : 0.125max.(C≥3.3μF) [F1, F6] W.V.: 25Vmin. : 0.075max.(C<0.1μF) : 0.125max.(C≥0.1μF) W.V.: 16V/10V: 0.15max. W.V.: 6.3V: 0.2max. | The charge/discharge current is less than 50mA. •Initial measurement for high dielectric constant type. Apply 200% of the rated DC voltage at the maximun operating temperature ±3°C for one hour. Remove and set for 48±4 hours at room temperature. Perform initial measurement. | | | |
| | I.R. | More than 1,000M Ω or 50 Ω •F (| Whichever is smaller) | | | | |

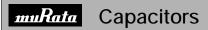


Table A-1

(1)

| | | Capacitance Change from 25℃ (%) | | | | | | |
|-------|---------------------------|---------------------------------|----------------|------|-------|------|-------|--|
| Char. | Nominal Values (ppm/°C)*1 | _ | -55 | | -30 | | -10 | |
| | | Max. | Min. | Max. | Min. | Max. | Min. | |
| 5C | 0± 30 | 0.58 | -0.24 | 0.40 | -0.17 | 0.25 | -0.11 | |
| 6C | 0± 60 | 0.87 | -0.48 | 0.59 | -0.33 | 0.38 | -0.21 | |
| 6P | -150± 60 | 2.33 | 0.72 | 1.61 | 0.50 | 1.02 | 0.32 | |
| 6R | -220± 60 | 3.02 | 1.28 | 2.08 | 0.88 | 1.32 | 0.56 | |
| 6S | -330± 60 | 4.09 | 2.16 | 2.81 | 1.49 | 1.79 | 0.95 | |
| 6T | -470± 60 | 5.46 | 3.28 | 3.75 | 2.26 | 2.39 | 1.44 | |
| 7U | -750±120 | 8.78 | 5.04 | 6.04 | 3.47 | 3.84 | 2.21 | |
| 1X | +350 to -1000 | _ | _ | _ | _ | _ | _ | |

^{*1}Nominal values denote the temperature coefficient within a range of 25°C to 125°C (for Δ C)/85°C (for other TC).

(2)

| (2) | | | | | | | | | |
|-------|--------------------------|---------------------------------|------------|------|-------------|------|-------|--|--|
| | | Capacitance Change from 20℃ (%) | | | | | | | |
| Char. | Nominal Values (ppm/℃)*2 | - | -55 | | -2 5 | | -10 | | |
| | - | Max. | Min. | Max. | Min. | Max. | Min. | | |
| 2C | 0± 60 | 0.82 | -0.45 | 0.49 | -0.27 | 0.33 | -0.18 | | |
| 3C | 0±120 | 1.37 | -0.90 | 0.82 | -0.54 | 0.55 | -0.36 | | |
| 4C | 0±250 | 2.56 | -1.88 | 1.54 | -1.13 | 1.02 | -0.75 | | |
| 2P | -150 ± 60 | _ | _ | 1.32 | 0.41 | 0.88 | 0.27 | | |
| 3P | -150±120 | _ | _ | 1.65 | 0.14 | 1.10 | 0.09 | | |
| 4P | -150±250 | _ | _ | 2.36 | -0.45 | 1.57 | -0.30 | | |
| 2R | -220 ± 60 | _ | _ | 1.70 | 0.72 | 1.13 | 0.48 | | |
| 3R | -220±120 | _ | _ | 2.03 | 0.45 | 1.35 | 0.30 | | |
| 4R | -220±250 | _ | _ | 2.74 | -0.14 | 1.83 | -0.09 | | |
| 2S | -330 ± 60 | _ | _ | 2.30 | 1.22 | 1.54 | 0.81 | | |
| 3S | -330±120 | _ | _ | 2.63 | 0.95 | 1.76 | 0.63 | | |
| 4S | -330±250 | _ | _ | 3.35 | 0.36 | 2.23 | 0.24 | | |
| 2T | -470 ± 60 | _ | _ | 3.07 | 1.85 | 2.05 | 1.23 | | |
| 3T | -470±120 | _ | _ | 3.40 | 1.58 | 2.27 | 1.05 | | |
| 4T | -470±250 | _ | - | 4.12 | 0.99 | 2.74 | 0.66 | | |
| 3U | -750±120 | _ | _ | 4.94 | 2.84 | 3.29 | 1.89 | | |
| 4U | -750±250 | _ | _ | 5.65 | 2.25 | 3.77 | 1.50 | | |

^{*2}Nominal values denote the temperature coefficient within a range of 20°C to 125°C (for Δ C)/85°C (for other TC).

Monolithic Ceramic Capacitors GR_R6/R7/F5/E4 (X5R/X7R/Y5V/Z5U)

High Dielectric Constant Type 100V

| Part Number | TC Code | Rated Voltage (Vdc) | Capacitance* | Length L (mm) | Width W (mm) | Thickness T (mm) |
|-------------------|-----------|------------------------|--------------------|------------------|-----------------|---------------------|
| GRM188R72A222KD01 | X7R (EIA) | 100 | 2200pF±10% | 1.6 | 0.8 | 0.80 |
| GRM188R72A332KD01 | X7R (EIA) | 100 | 3300pF±10% | 1.6 | 0.8 | 0.80 |
| GRM219R72A472KA01 | X7R (EIA) | 100 | 4700pF±10% | 2.0 | 1.25 | 0.90 |
| GRM219R72A682KA01 | X7R (EIA) | 100 | 6800pF±10% | 2.0 | 1.25 | 0.90 |
| GRM21BR72A103KA01 | X7R (EIA) | 100 | 10000pF±10% | 2.0 | 1.25 | 1.25 |
| GRM31MR72A333KA01 | X7R (EIA) | 100 | 33000pF±10% | 3.2 | 1.6 | 1.15 |
| GRM31MR72A473KA01 | X7R (EIA) | 100 | 47000pF±10% | 3.2 | 1.6 | 1.15 |
| GRM32NR72A683KA01 | X7R (EIA) | 100 | 68000pF±10% | 3.2 | 2.5 | 1.35 |
| GRM32NR72A104KA01 | X7R (EIA) | 100 | 0.1μF±10% | 3.2 | 2.5 | 1.35 |
| GRM43RR72A154KA01 | X7R (EIA) | 100 | 0.15μF±10% | 4.5 | 3.2 | 1.80 |
| GRM43RR72A224KA01 | X7R (EIA) | 100 | 22000pF±10% | 4.5 | 3.2 | 1.80 |
| GRM43DR72A474KA01 | X7R (EIA) | 100 | 0.47μF±10% | 4.5 | 3.2 | 2.00 |
| GRM55DR72A105KA01 | X7R (EIA) | 100 | 1μF ±10% | 5.7 | 5.0 | 2.00 |
| GRM188F52A472ZD01 | Y5V (EIA) | 100 | 4700pF +80%, -20% | 1.6 | 0.8 | 0.80 |
| GRM32NF52A104ZA01 | Y5V (EIA) | 100 | 10000pF +80%, -20% | 3.2 | 2.5 | 1.35 |
| GRM55RF52A474ZA01 | Y5V (EIA) | 100 | 0.47μF +80%, -20% | 5.7 | 5.0 | 1.80 |

Monolithic Ceramic Capacitors GR_R6/R7/F5/E4 (X5R/X7R/Y5V/Z5U)

Thin Layer Large-Capacitance type

| Part Number | | Dime | nsions (mi | m) | | |
|----------------|-----------|-----------|---------------|-------------|--------|---------------|
| rait ivuilibei | L | W | T | e min. | g min. | - |
| GRM033 | 0.6 ±0.03 | 0.3 ±0.03 | 0.3 ±0.03 | 0.1 to 0.2 | 0.2 | S |
| GRM155 | 1.0 ±0.05 | 0.5 ±0.05 | 0.5 ±0.05 | 0.15 to 0.3 | 0.4 | 2 5 2 5 |
| GRM185 | 1.6 ±0.1 | 0.8 ±0.1 | 0.5 +0/-0.2 | 0.2 to 0.5 | 0.5 | 20202 |
| GRM188 | 1.6 ±0.1 | 0.8 ±0.1 | 0.8 ± 0.1 | 0.2 to 0.5 | 0.5 | |
| GRM216 | | | 0.6 ±0.1 | | | |
| GRM219 | 2.0 ±0.1 | 1.25 ±0.1 | 0.85 ±0.1 | 0.2 to 0.7 | 0.7 | |
| GRM21B | | | 1.25 ±0.1 | | | |
| GRM316 | | | 0.6 ±0.1 | | | |
| GRM319 | 3.2 ±0.15 | 1.6 ±0.15 | 0.85 ±0.1 | 0.3 to 0.8 | 1.5 | e g e |
| GRM31M |] | | 1.15 ±0.1 | 0.3 10 0.6 | 1.5 | - |
| GRM31C | 3.2 ±0.2 | 1.6 ±0.2 | 1.6 ±0.2 | | | |
| GRM32D | 3.2 ±0.3 | 2.5 +0.2 | 2.0 ±0.2 | 0.3 | 1.0 | |
| GRM32E | 3.2 ±0.3 | 2.5 ±0.2 | 2.5 ±0.2 | 0.3 | 1.0 | |
| GRM43D | | | 2.0 ±0.2 | | | T T |
| GRM43E | 4.5 ±0.4 | 3.2 ±0.3 | 2.5 ±0.2 | 0.3 | 2.0 | <u> </u> |
| GRM43S | | | 2.8 ±0.2 | | | L W |
| GRM55F | 5.7 ±0.4 | 5.0 ±0.4 | 3.2 ±0.2 | 0.3 | 2.0 | |

| Part Number | TC Code | Rated Voltage (Vdc) | Capacitance* | Length L (mm) | Width W (mm) | Thickness T (mm) |
|-------------------|-----------|------------------------|-----------------|------------------|-----------------|---------------------|
| GRM155R60J154KE01 | X5R (EIA) | 6.3 | 0.15μF±10% | 1.0 | 0.5 | 0.50 |
| GRM155R60J224KE01 | X5R (EIA) | 6.3 | 22000pF±10% | 1.0 | 0.5 | 0.50 |
| GRM155R60J334KE01 | X5R (EIA) | 6.3 | 0.33 μF±10% | 1.0 | 0.5 | 0.50 |
| GRM155R60J474KE19 | X5R (EIA) | 6.3 | 0.47μF±10% | 1.0 | 0.5 | 0.50 |
| GRM188R60J225KE01 | X5R (EIA) | 6.3 | 2.2μF ±10% | 1.6 | 0.8 | 0.80 |
| GRM219R60J475KE01 | X5R (EIA) | 6.3 | 4.7μF ±10% | 2.0 | 1.25 | 0.90 |
| GRM21BR60J106KE01 | X5R (EIA) | 6.3 | 10μF ±10% | 2.0 | 1.25 | 1.25 |
| GRM21BR60J106ME01 | X5R (EIA) | 6.3 | 10μF ±20% | 2.0 | 1.25 | 1.25 |
| GRM32DR60J226KA01 | X5R (EIA) | 6.3 | 22μF ±10% | 3.2 | 2.5 | 2.00 |
| GRM32ER60J476ME20 | X5R (EIA) | 6.3 | 47μF ±20% | 3.2 | 2.5 | 2.50 |
| GRM43SR60J107ME20 | X5R (EIA) | 6.3 | 100μF ±20% | 4.5 | 3.2 | 2.80 |
| GRM55FR60J107KA01 | X5R (EIA) | 6.3 | 100μF ±10% | 5.7 | 5.0 | 3.20 |
| GRM55FR60J107MA01 | X5R (EIA) | 6.3 | 100μF ±20% | 5.7 | 5.0 | 3.20 |
| GRM21BF50J106ZE01 | Y5V (EIA) | 6.3 | 10μF +80%, -20% | 2.0 | 1.25 | 1.25 |

| No. | Ite | em | Specifications | | | Test Method | | | | |
|-----|---|--|--|--|---|--|---|--|--|--|
| 1 | Operating Temperat Range | | B1, B3, F1: -25°C to +85°C R6: -55°C to +85°C F5: -30°C to +85°C C8: -55°C to +105°C, C7: -55°C to +125°C | | | Reference Temperature : 25℃ (B1, B3, F1 : 20℃) | | | | |
| 2 | Rated Vo | ltage | See the previous pages | | may be ap When AC whichever | The rated voltage is defined as the maximum voltage which nay be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V ^{p,p} or V ^{o,p} , whichever is larger, should be maintained within the rated roltage range. | | | | |
| 3 | Appearan | nce | No defects or abnormaliti | ies | Visual insp | Visual inspection | | | | |
| 4 | Dimensio | ns | Within the specified dime | ensions | Using calip | pers | | | | |
| 5 | Dielectric | Strength | No defects or abnormaliti | ies | is applied b | No failure should be observed when 250% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA. | | | | |
| 6 | Insulation Resistance | | More than 50Ω • F | | not exceed 75%RH ma | The insulation resistance should be measured with a DC not exceeding the rated voltage at Reference Temperatur 75%RH max. and within 1 minutes of charging, provided charge/discharge current is less than 50mA. | | | | |
| 7 | Capacitance | | Within the specified tolers | *Table 1 GRM155 B3/R6 1A 124 to 224 GRM185 B3/R6 1A 105 GRM188 B3/R6 1C/1A 225 GRM219 B3/R6 1A 475 GRM21B B3/R6 1C/1A 106 | Temperatu C≤10 C≤10 C>10 *1 Hov | apacitance µF (10V min.)*1 µF (6.3V max.) µF | rand voltage Frequency 1±0.1kHz 1±0.1kHz 120±24Hz | shown in the table. | | |
| 8 | Dissipation Factor (D.F.) | | B1, B3, R6, C7, C8 : 0.1 F1, F5 : 0.2 max. | *Table 1 GRM155 B3/R6 1A 124 to 224 GRM185 B3/R6 1A 105 GRM188 B3/R6 1C/1A 225 GRM219 B3/R6 1A 475 GRM21B B3/R6 1C/1A 106 | frequency | and voltage shown apacitance µF (10V min.)*1 µF (6.3V max.) µF | in the table. Frequency 1±0.1kHz 1±0.1kHz 1±0.24Hz | Voltage 1.0±0.2Vrms 0.5±0.1Vrms 0.5±0.1Vrms Vrms about Table 1 | | |
| | | No bias B1, B3: Within +/-10% (-25°C to +85°C) F1: Within +30/-80% (-25°C to +85°C) R6: Within +/-15% (-55°C to +85°C) F5: Within +22/-82% (-30°C to +85°C) C7: Within +/-22% (-55°C to +125°C) C8: Within +/-22% (-55°C to +105°C) | | | The capacitance change should be measu each specified temp. stage. The ranges of capacitance change compar Reference Temperature value over the tem shown in the table should be within the spe In case of applying voltage, the capacitance measured after 1 more min. with applying vequilibration of each temp. stage. *GRM43 B1/R6 0J/1A 336/476 only: 1.0± | | | ared with the mperature ranges ecified ranges.* ce change should be voltage in | | |
| 9 | Capacitance Temperature Characteristics | | | | 2 3 | Temperature Reference Temp -55±3 (for R6, -25±3 (for B1, -30±3 (for Reference Temp | C7, C8)/ B3, F1) F5) ereture±2 | Applying Voltage (V) No bias | | |
| | | 50% of the Rated Voltage | B1: Within +10/-30% F1: Within +30/-95% | | | 85±3 (for B1, B3, 125±3 (for 105±3 (for 20±2 | C7)/ | | | |
| | | 3- | | 6 | −25±3 (for B | 31, F1) | 50% of the rated | | | |
| | | | | | 7 | 20±2 | | voltage | | |
| | | | | 8 | 85±3 (for B1 | 7 | | | | |

Continued on the following page.

Perform the initial measurement.



| No. | Item | Specifications | Test Method | | | | |
|-----|---------------------------------|--|--|--|---|--|--|
| | | No removal of the terminations or other defects should occur | Solder the capacitor on the test jig (glass epoxy board) shown in Fig. 1a using an eutectic solder. Then apply 10N* force in parallel with the test jig for 10+/−1sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. *5N: GR□15/GRM18, 2N: GR□33 | | | | |
| 10 | Adhesive Strength | | Type GR□03 | a 0.3 | b 0.9 | 0.3 | |
| | of Termination | | GR□15 | 0.4 | 1.5 | 0.5 | |
| | | VA VA VA VA VA Solder resist | GRM18 | 1.0 | 3.0 | 1.2 | |
| | | Baked electrode or | GRM21 | 1.2 | 4.0 | 1.65 | |
| | | copper foil | GRM31 | 2.2 | 5.0 | 2.0 | |
| | | • | GRM32 | 2.2 | 5.0 | 2.9 | |
| | | Fig. 1a | GRM43 | 3.5 | 7.0 | 3.7 | |
| | | | | 4.5 | 8.0 | 5.6 | |
| | | | GRM55 | 4.5 | 0.0 | 5.0 | |
| | Appearance | No defects or abnormalities | Solder the capacito | or on the test ii | a (alass epoxy | board) in the | |
| 11 | Capacitance Vibration D.F. | Within the specified tolerance B1, B3, R6, C7, C8: 0.1 max. F1, F5: 0.2 max. | same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmon having a total amplitude of 1.5mm, the frequency being uniformly between the approximate limits of 10 and 5 frequency range, from 10 to 55Hz and return to 10Hz be traversed in approximately 1 minute. This motion applied for a period of 2 hours in each 3 mutually perdirections (total of 6 hours). | | | s (10). sarmonic motion by being varied and 55Hz. The 10Hz, should btion should be | |
| | | No cracking or marking defects should occur | Solder the capacito | or on the test ji | g (glass epoxy | board) shown | |
| 12 | Deflection | 20 50 Pressunzing speed: 1.0mm/sec. Pressunze R230 Flexure: ≤1 Capacitance meter | in Fig. 2a using an direction shown in be done either with should be conduct and free of defects | Fig. 3a for 5+/ an an iron or usined with care so | 1 sec. The sing the reflow no that the solde shock. | oldering should nethod and | |
| | | 45 45 | | 1 lg. 2 | | □45 . t . 0.0mm) | |
| | | | _ | | | □15 : t : 0.8mm) | |
| | | Fig.3a | Type | a | b | С | |
| | | ı ıy.sa | _GR□03 | 0.3 | 0.9 | 0.3 | |
| | | | GR□15 | 0.4 | 1.5 | 0.5 | |
| | | | GRM18 | 1.0 | 3.0 | 1.2 | |
| | | | GRM21 | 1.2 | 4.0 | 1.65 | |
| | | | GRM31 | 2.2 | 5.0 | 2.0 | |
| | | | GRM32 | 2.2 | 5.0 | 2.9 | |
| | | | GRM43 | 3.5 | 7.0 | 3.7 | |
| | | | GRM55 | 4.5 | 8.0 | 5.6 | |
| | | | | | | (in mm) | |
| 13 | Solderability of Termination | 75% of the terminations is to be soldered evenly and continuously | Immerse the capacitor in a solution of ethanol (JIS-K-8101) a rosin (JIS-K-5902) (25% rosin in weight propotion) . Preheat at 80 to 120℃ for 10 to 30 seconds. After preheating, immerse in an eutectic solder solution for 2+/−0.5 seconds at 230+/−5℃. | | | | |

| No. | Ite | em | Specifications | Test Method | | | | | | |
|----------|---|---|---|---|--|---------------------|-----------------------------------|---------------|--|--|
| | Resistance to Soldering Heat | Appearance Capacitance Change Q/D.F. I.R. | No defects or abnormalities B1, B3, R6, C7, C8: Within ±7.5% F1, F5: Within ±20% B1, B3, R6, C7, C8: 0.1 max. F1, F5: 0.2 max. More than 50Ω • F | Preheat the capacitor at 120 to 150°C for 1 minute. Immerse the capacitor in an eutectic solder solution at 270+/−5°C for 10+/−0.5 seconds. Set at room temperature fo 24+/−2 hours (temperature compensating tyoe) or 48+/−4 hours (high dielectric constant type), then measure. •Initial measurement for high dielectric constant type | | | | | | |
| 14 | | Dielectric Strength | No defects | then set at roo Perform the in | Perform a heat treatment at 150+0/-10°C for one hour and then set at room temperature for 48+/-4 hours. Perform the initial measurement. *Preheating for GRM32/43/55 | | | | | |
| | | | | | | | | | | |
| | | | | Step 1 | • | erature to 120°C | | me min | | |
| | | | | 2 | | to 200℃ | | min. min. | | |
| \dashv | | Appearance | No defects or abnormalities | | | | in the same m | | | |
| | | | | | ne conditions a | | in the came in | armor arm | | |
| | | Capacitance Change | B1, B3, R6, C7, C8 : Within ±7.5% F1, F5 : Within ±20% | | ve cycles according to the four heat treatments | | | | | |
| | | onungo | , | | shown in the following table. | | | | | |
| | | D.F. | B1, B3, R6, C7, C8 : 0.1 max. F1, F5 : 0.2 max. | Set for 24+/-2 hours (temperature compensating type) or 48+/-4 hours (high dielectric constant type) at room | | | | | | |
| | | I.R. | More than 50Ω • F | | temperature, then measure. | | 1, 60, 41.00 | • | | |
| | Temperature | | Wore than 3022 - 1 | Cton | 1 | 1 2 | 2 | 1 | | |
| 5 | Sudden | Dielectric Strength | No defects | Step | Min. | 2 | 3 Max. | 4 | | |
| | High Temperature High Humidity (Steady) | 3. | | Temp. (°C) | Operating Temp. +0/-3 | Room Temp. | Operating Temp. +3/-0 | Room Temp. | | |
| | | | | Time (min.) | 30±3 | 2 to 3 | 30±3 | 2 to 3 | | |
| | | Appearance Capacitance Change | No defects or abnormalities B1, B3, R6, C7, C8 : Within ±12.5% F1, F5 : Within ±30% | Perform a hea then set at roc Perform the in Apply the rate | ement for high dielectric constant type t treatment at 150+0/-10°C for one hour a m temperature for 48+/-4 hours. itial measurement. d voltage at 40+/-2°C and 90 to 95% hum irs. The charge/discharge currentis less the | | | | | |
| 16 | | D.F. | B1, B3, R6, C7, C8 : 0.2 max. F1, F5 : 0.4 max. More than 12.5Ω • F | Perform a hea then let sit for | Initial measurement Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 48+/-4 hours at room temperature. Perform the initial measurement. Measurement after test Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 48+/-4 hours at room temperature, then measure. | | | | | |
| | | | | Perform a hea then let sit for | | | | | | |
| | | Appearance | No defects or abnormalities | | | • | 000 + /–12 hou | | | |
| | Durability | Capacitance Change | B1, B3, R6, C7, C8 : Within ±12.5% F1, F5 : Within ±30% | hours at room | temperature, t | then mea | | 18+/-4 | | |
| | | D.F. | B1, B3, R6, C7, C8 : 0.1 max. F1, F5 : 0.4 max. | - | The charge/ discharge current is less than 50mA. Initial measurement | | | | | |
| 7 | | I.R. | More than 25Ω • F | | 48+/-4 hours | | 10℃ for one ho temperature. P | | | |
| | | | | | it treatment at | | 10℃ for one ho temperature, th | | | |